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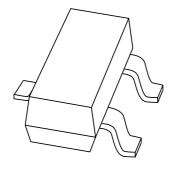
If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## PMBT4401 NPN switching transistor

Product data sheet Supersedes data of 1999 Apr 15 2004 Jan 21



NXP Semiconductors Product data sheet

## **NPN** switching transistor

**PMBT4401** 

#### **FEATURES**

- High current (max. 600 mA)
- Low voltage (max. 40 V).

#### **APPLICATIONS**

• Industrial and consumer switching applications.

#### **DESCRIPTION**

NPN switching transistor in a SOT23 plastic package. PNP complement: PMBT4403.

#### **MARKING**

TYPE NUMBER	MARKING CODE(1)			
PMBT4401	*2X			

#### Note

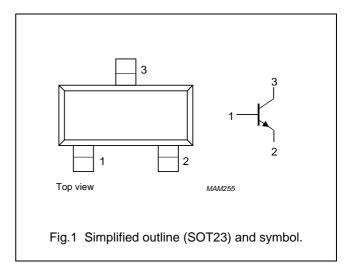
1. \* = p: Made in Hong Kong.

\* = t : Made in Malaysia.

\* = W : Made in China.

#### **PINNING**

PIN	DESCRIPTION
1	base
2	emitter
3	collector



#### **ORDERING INFORMATION**

TYPE	PACKAGE					
NUMBER NAME		DESCRIPTION	VERSION			
PMBT4401	-	plastic surface mounted package; 3 leads	SOT23			

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	PARAMETER CONDITIONS		MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	6	V
I <sub>C</sub>	collector current (DC)		_	600	mA
I <sub>CM</sub>	peak collector current		_	800	mA
I <sub>BM</sub>	peak base current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

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## NPN switching transistor

PMBT4401

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th (j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 60 V	_	50	nA
I <sub>EBO</sub>	emitter-base cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 6 V	_	50	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; (see Fig.2)			
		$I_{C} = 0.1 \text{ mA}$	20	_	
		$I_C = 1 \text{ mA}$	40	_	
		I <sub>C</sub> = 10 mA	80	_	
		I <sub>C</sub> = 150 mA; note 1	100	300	
		I <sub>C</sub> = 500 mA; V <sub>CE</sub> = 2 V; note 1	40	_	
V <sub>CEsat</sub>	collector-emitter saturation	I <sub>C</sub> = 150 mA; I <sub>B</sub> = 15 mA; note 1	_	400	mV
volta	voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; note 1	_	750	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 150 mA; I <sub>B</sub> = 15 mA; note 1	_	950	mV
		I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; note 1	_	1.2	٧
C <sub>c</sub>	collector capacitance	$I_E = I_e = 0$ ; $V_{CB} = 5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	8	pF
C <sub>e</sub>	emitter capacitance	$I_C = I_c = 0$ ; $V_{EB} = 500 \text{ mV}$ ; $f = 1 \text{ MHz}$	_	30	pF
f <sub>T</sub>	transition frequency	$I_C = 20 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	250	_	MHz
Switching ti	imes (between 10% and 90% leve	<b>ls)</b> ; (see Fig.3)			
t <sub>on</sub>	turn-on time	I <sub>Con</sub> = 150 mA; I <sub>Bon</sub> = 15 mA;	_	35	ns
t <sub>d</sub>	delay time	$I_{Boff} = -15 \text{ mA}$	_	15	ns
t <sub>r</sub>	rise time		_	20	ns
t <sub>off</sub>	turn-off time		_	250	ns
t <sub>s</sub>	storage time		_	200	ns
t <sub>f</sub>	fall time		_	60	ns

#### Note

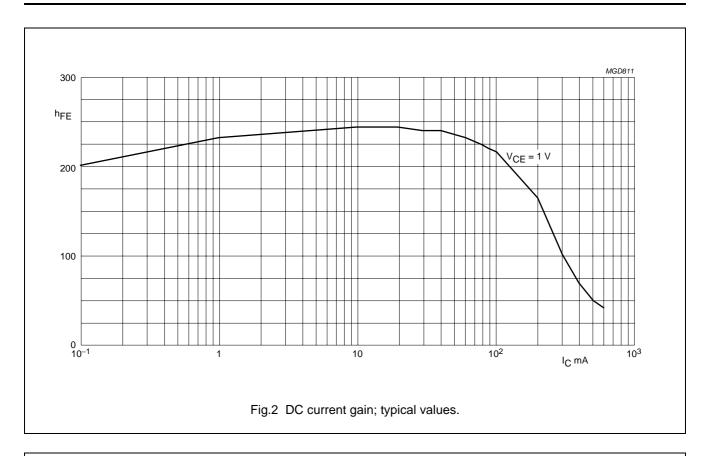
1. Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

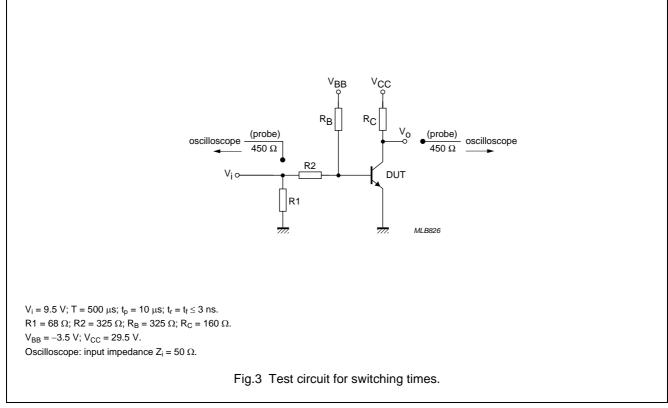
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## NPN switching transistor

## PMBT4401





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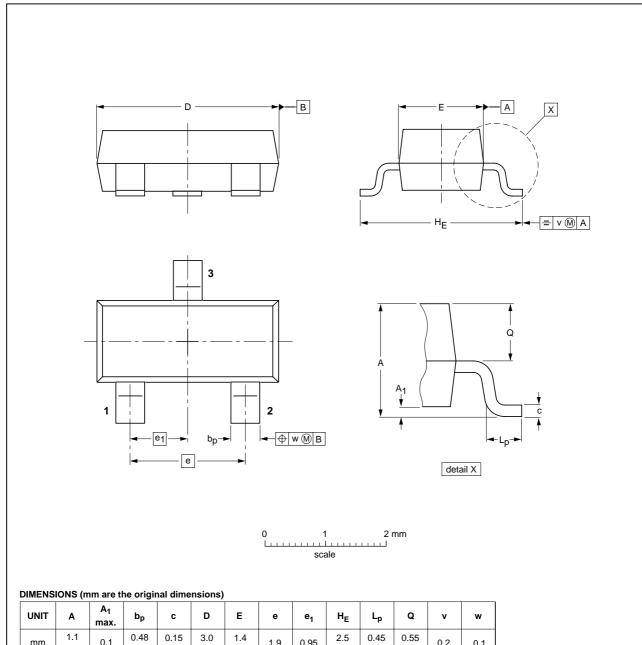
## NPN switching transistor

## PMBT4401

SOT23

#### **PACKAGE OUTLINE**

#### Plastic surface-mounted package; 3 leads



ι	JNIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	v	w
	mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE		REFER	REFERENCES		REFERENCES EUROPEAN			ISSUE DATE
VERSION	IEC	EC JEDEC JEITA		PROJECTION	ISSUE DATE			
SOT23		TO-236AB				<del>-04-11-04</del> 06-03-16		

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NXP Semiconductors Product data sheet

## NPN switching transistor

**PMBT4401** 

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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## **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com
For sales offices addresses send e-mail to: salesaddresses@nxp.com

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